

PRODUCT DATASHEET

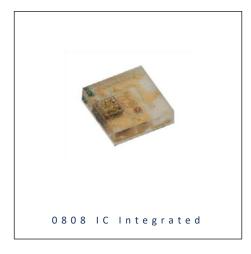


- ► CHIP SMD with IC
- ▶ 0808 (2020) IC 0.75t
- ► Red/Green/Blue

NOM50S17IC











Release Date: 22 April 2021 Version: A1.1

- **FEATURES:**
- Package: CHIP EIA STD Package with Integrated IC Sleep Mode Type 102
- Forward Current: 20mA
- Forward Voltage (typ.): +4.5~+5.5V
- Luminous Intensity (typ.): 1000mcd mixed white
- Colour: Red/Green/Blue
- Wavelength: 622/527/467nm
- Viewing angle: 120°
- **Materials:**
 - Resin: Silicone (Water Diffused)
 - L/F Finish: Ag Plated
- Operating Temperature: -40~+85°C
- Storage Temperature: -40~+105°C
- IC Feature: Serial data transmission signal by DATA CLK two lines. In sleep mode the LED current is lower than $5\mu A$.
- Pixel: One pixel contains R, G, and B colour that each can achieve 256 level brightness grayscales, which forms 16,777,216 combination colours.
- Soldering methods: IR Reflow soldering
- Preconditioning: acc. to JEDEC Level 5
 - Packing: 8mm tape with Max.4000pcs/reel, ø180mm (7")

APPLICATIONS:

- Telecommunication
- Indicator
- Home Appliance
- **Decoration Lighting**
- Full Colour LED Strip
- **Gaming Device**

Support sleep/wake up mode. In sleep mode the LED's current was lower than 5µA



CHARACTERISTICS:

Absolute Maximum Characteristics (Ta=25°C)

Parameter	Symbol	Ratings	Unit
The Max. LED Output Current	Іомах	20/channel	mA
Rate of Data Signal	Fclk	15	MHz
IC Power Supply Voltage	V_{DD}	<6.5	V
Power Dissipation	P _D	<400	mW
Operating Temperature	TOPR	-40~+85	°C
Storage Temperature	T _{STG}	-40~+105	°C
Soldering Temperature	T _{SD}	260	°C

Electrical & Optical Characteristics (Ta=25°C, V_{DD}=5V)

Parameter		Symbol		Values	Unit	Test	
		Syllibol	Min.	Тур.	Max.	Offic	Condition
Forward Voltage		V _F	4.5		5.5	V	I _F =20mA
	R			430		mcd	I _F =20mA
Luminous Intensity	G	lv		750			
Luminous Intensity	В	IV		140			
	W			1000			
	R	λο	615		630	nm	I _F =20mA
Dominant Wavelength	G		520		535		
	В		460		475		
Colour Coordinate	Х			0.2400			I _F =20mA
Colour Coordinate	Υ			0.2500			II-ZUIIIA
Viewing Angle		2θ _{1/2}		120		deg	I _F =20mA



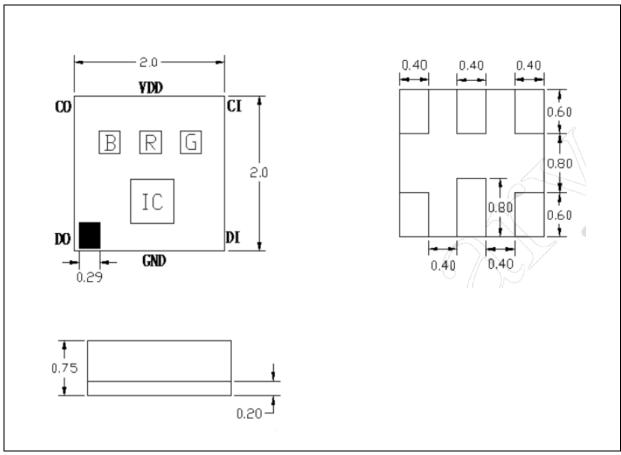
Electrical & Optical Characteristics (Ta=25°C, V_{DD}=5V)

Darameter	Symbol		Unit	Test		
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Supply Voltage	V_{DD}	4.5	5.0	5.5	V	
Input Voltage Level	V _{IH}	2.7		V _{DD} +0.4	V	
Input Voltage Level	VIL	-0.4		1.0	V	
Clock High Level Width	Тськн	30			ns	
Clock Low Level Width	T _{CLKL}	30			ns	
Data Set-Up Time	Тѕетир	10			ns	
Data Hold Time	T _{HOLD}	5			ns	
Working Current (IC)	I _{DD}			2	mA	I _{out} =OFF
Static Current	I _{sleep}			5	μΑ	Sleep Mode
ESD Pressure (HBM)	V _{ESD}		6000		V	



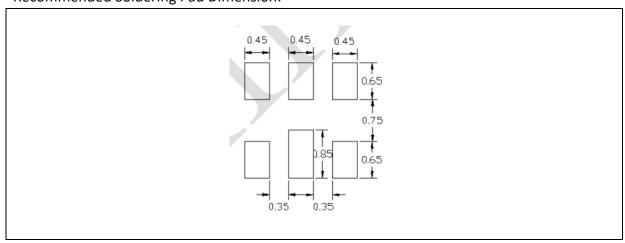
OUTLINE DIMENSION:

Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.2mm, unless otherwise noted.

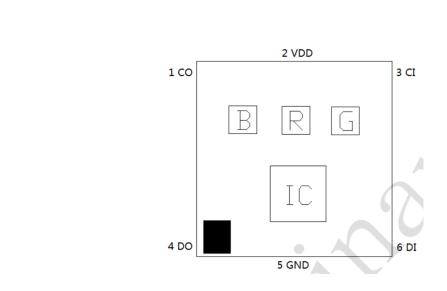
Recommended Soldering Pad Dimension:



- 1. Dimensions are in millimetre (mm).
- 2. Tolerance ±0.1mm with angle tolerance ±0.5°.



PIN CONFIGURATION:



No.	Symbol	Function Description
1	СО	Clock Output
2	VDD	Supply Voltage
3	CI	Clock Input
4	DO	Data Output
5	GND	Ground
6	DI	Data Input



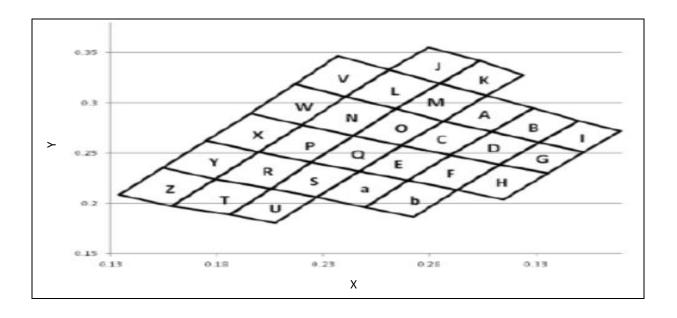
BINNING GROUPS:

Luminous Intensity Classifications (White) (I_F = 20mA, V_{DD}=5V):

Code	Min.	Max.	Unit
13	600	780	
14	780	1000	
15	1000	1300	mcd
16	1300	1700	
17	1700	2200	



CIE CHROMATICITY DIAGRAM:



Chromaticity Coordinates Classifications (I_F = 20mA):

	1	1	2	2	3	3	2	1
	Х	Υ	Х	Υ	Х	Υ	Х	Υ
А	0.3070	0.3072	0.3287	0.2948	0.3091	0.2712	0.2865	0.2819
В	0.3287	0.2948	0.3504	0.2824	0.3318	0.2605	0.3091	0.2712
С	0.2865	0.2819	0.3091	0.2712	0.2899	0.2482	0.2667	0.2578
D	0.3091	0.2712	0.3318	0.2605	0.3132	0.2387	0.2899	0.2482
E	0.2667	0.2578	0.2899	0.2482	0.2700	0.2227	0.2470	0.2320
F	0.2899	0.2482	0.3132	0.2387	0.2930	0.2134	0.2700	0.2227
G	0.3318	0.2605	0.3524	0.2513	0.3358	0.2299	0.3132	0.2387
Н	0.2930	0.2134	0.3132	0.2387	0.3358	0.2299	0.3150	0.2040
I	0.3318	0.2605	0.3504	0.2824	0.3695	0.2719	0.3524	0.2513
J	0.2609	0.3332	0.2797	0.3550	0.3036	0.3420	0.2849	0.3196
K	0.2851	0.3196	0.3036	0.3420	0.3243	0.3280	0.3068	0.3072
L	0.2406	0.3064	0.2609	0.3332	0.2849	0.3196	0.2643	0.294
М	0.2643	0.294	0.2849	0.3196	0.3068	0.3072	0.2865	0.2819
N	0.2200	0.2783	0.2406	0.3064	0.2643	0.2940	0.2444	0.2672
0	0.2444	0.2672	0.2643	0.2940	0.2865	0.2819	0.2667	0.2578
Р	0.2200	0.2783	0.1996	0.2513	0.2244	0.2407	0.2444	0.2672
Q	0.2444	0.2672	0.2244	0.2407	0.2471	0.2320	0.2669	0.2579

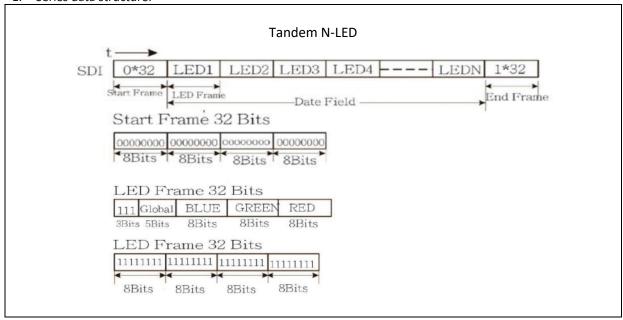


R	0.1996	0.2513	0.1792	0.2243	0.2056	0.2148	0.2244	0.2407
Т	0.1792	0.2243	0.1588	0.1973	0.1862	0.1886	0.2056	0.2148
U	0.2056	0.2148	0.1862	0.1886	0.2075	0.1802	0.2273	0.2061
Х	0.1960	0.2894	0.1752	0.2624	0.1996	0.2513	0.2200	0.2783
Υ	0.1752	0.2624	0.1548	0.2354	0.1792	0.2243	0.1996	0.2513
Z	0.1548	0.2354	0.1344	0.2084	0.1588	0.1973	0.1792	0.2243
S	0.2244	0.2407	0.2056	0.2148	0.2273	0.2061	0.2471	0.2320
а	0.2471	0.2320	0.2273	0.2061	0.2498	0.1959	0.2700	0.2227
b	0.2700	0.2227	0.2498	0.1959	0.2728	0.1866	0.2930	0.2134
V	0.2169	0.3188	0.2369	0.3468	0.2609	0.3332	0.2406	0.3064
W	0.1963	0.2907	0.2169	0.3188	0.2406	0.3064	0.2200	0.2783



Function Description:

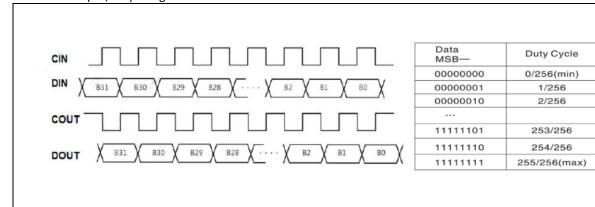
1. Series data structure:



2. 5-Bit (level 32) brightness adjustment (simultaneous control of OUTR/OUTG/OUTB three port current):

DATA MSB ←→ LSB	Driving Current
00000	0/31
00001	1/31
00010	2/31
•••	
11110	30/31
11111	31/31(max)

3. PWM input/output signal relations:

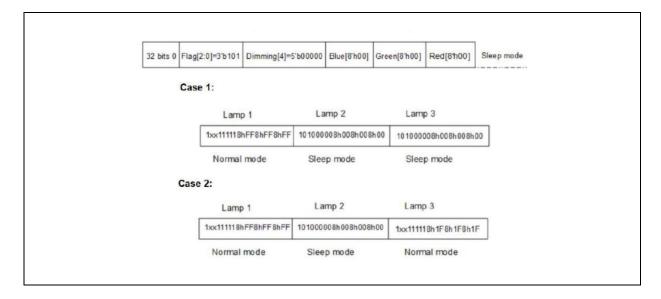




4. Sleep and power saving mode:

LED supports the sleep/wake-up modes for power saving purpose. After the IC receives 24-bits 0's BGR data (that is B[7:0]=8h00, G[7:0]=8h00, R[7:0]=8h00), in the meantime, both of the data in 3-bits FLAG and 5-bits DIMMING is 8h'A0' (that is FLAG[2:0]=3b101 and DIMMING[4:0]=5b00000), the IC will entre sleep mode, its current is about 1μ A.

The IC will wake-up from sleep mode once receiving the new data with the data of FLAG[2:0], DIMMING[4:0] is not 8h'A0'; after wake-up, all sleeping circuits in IC return to normal working mode within 1ms. Since it takes 1ms for a sleeping IC returning to normal function mode, it is recommended for a host to wait for 1ms to send display data and command after issuing a wake-up command.

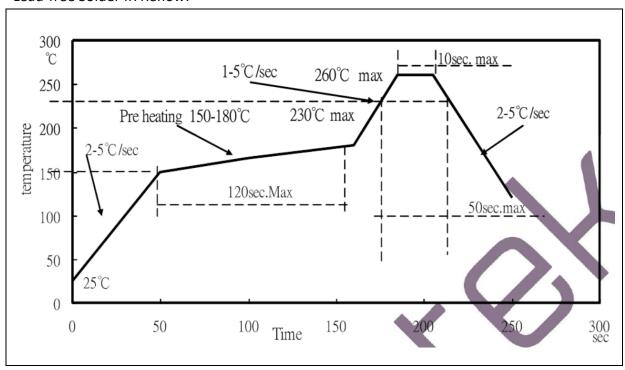


In case 2, while lamp 2 is under sleep mode, in the following data transfer process, the state of lamp 2 will be not changed as long as the 32-bits data for lamp 2 is received with data of FLAG[2:0] and DIMMING[4:0] being 8h"A0". It means lamp 2 will keep in sleep mode as well. In the situation, lamp 2 can pass through the remaining data to lamp 3 (32-bits) to change the display data of lamp 3. In other words, the sleeping chip is able to pass the data to the next chips.



RECOMMENDED SOLDERING PROFILE:

Lead-free Solder IR Reflow:



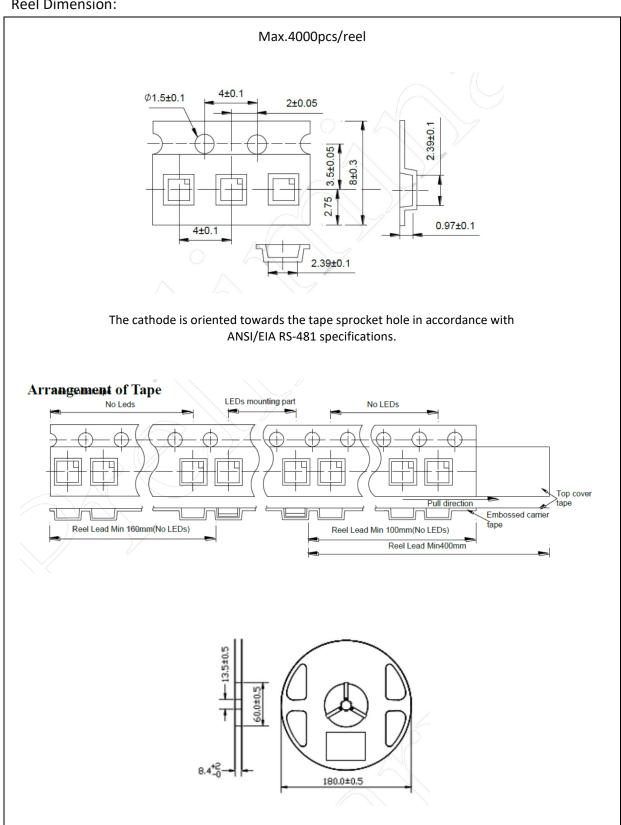
Note:

- 1. We recommend the reflow temperature 240°C (±5°C). The maximum soldering temperature should be limited to 260°C.
- 2. Maxima reflow soldering: 1 time.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.



PACKING SPECIFICATION:

Reel Dimension:





PRECAUTIONS OF USE:

Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within 24 hours. Otherwise, they should be kept in a damp-proof box with descanting agent stored at R.H.<20% and apply baking before use.

Over-Current Proof:

Must apply resistors for protection otherwise slight voltage shift will cause big current change and burnout will happen.

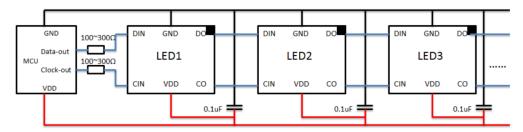
Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

• 60±3°C x 6hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

Testing Circuit:



When the first LED is connected to the MCU, a resistance R is needed in series between its signal input line and the MCU. The size of R depends on the number of cascade beads. The more cascade, the smaller resistance R is used. It is generally recommended that the value be between 100-1K. Usually the recommended value is around 300 R. In order to make the LEDs work more stably, a parallel capacitor is needed between VDD and GND of each.

Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.



REVISION RECORD:

Version	Date	Summary of Revision
A1.0	06/11/2019	Datasheet set-up.
A1.1	22/04/2021	Revise reel dimensions.